

# P24C128D

# I<sup>2</sup>C-Compatible Serial E<sup>2</sup>PROM

## **Data Sheet Rev.1.3**

# **General Description**

The P24C128D is 128-Kbit I<sup>2</sup>C-compatible Serial EEPROM (Electrically Erasable Programmable Memory) device. It contains a memory array of 16384 × 8bits, which is 64-byte per page. P24C128D provides the following devices for different application.

#### **Device Selection Table**

Device Name	Supply	Temp. Range	Max. Clock Frequency
P24C128D -MI	1.7V~5.5V	-40°C ~ 85°C	1MHz <sup>[1]</sup>
P24C128D -NK	1.8V~5.5V	-40°C~105°C	1MHz <sup>[1]</sup>
P24C128D -DE	2.5V~5.5V	-40°C~125°C	1MHz

Note 1: 400 kHz for  $V_{CC} < 2.5V$ .

## **Features**

- Single Supply Voltage and High Speed
  - ♦ Minimum operating voltage down to 1.7V
  - ♦ 1 MHz clock from 2.5V to 5.5V
  - ♦ 400kHz clock from 1.7V to 2.5V
- Low power CMOS technology
  - ♦ Read current 400uA, maximum
  - ♦ Write current 1.6mA, maximum
- Schmitt Trigger, Filtered Inputs for Noise Suppression
- Sequential & Random Read Features
- Page Write Modes, Partial Page Writes Allowed
- Write protection of the whole memory array
- Additional Write Lockable Page and 128-bit Serial Number
- Self-timed Write Cycle (5ms maximum)
- High Reliability

♦ Endurance: > 1 Million Write Cycles

♦ Data Retention: > 100 Years

→ ESD Protection (HBM): > 6KV

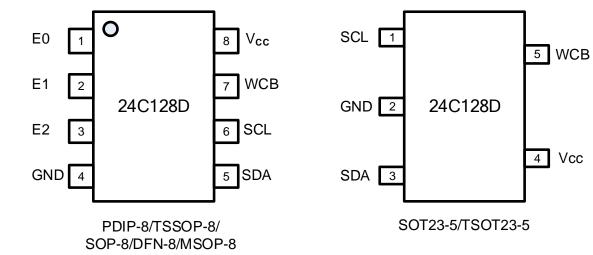
♦ Latch up Capability: +/- 200mA (25°C and 125°C)

Package: PDIP-8, SOP-8, TSSOP-8, MSOP-8, DFN-8/UDFN-8, SOT23-5, TSOT23-5

# 1. Pin Configuration

# 1.1 Pin Configuration

Figure 1-1 Pin Configuration



# 1.2 Pin Definition

Table 1-1 Pin Definition for PDIP-8/SOP-8/TSSOP-8/DFN-8/MSOP-8 Packages

Pin	Name	Туре	Description
1	E0	Input	Slave Address Setting Bit0
2	E1	Input	Slave Address Setting Bit1
3	E2	Input	Slave Address Setting Bit2
4	GND	Ground	Ground
5	SDA	I/O	Serial Data Input and Serial Data Output
6	SCL	Input	Serial Clock Input
7	WCB	Input	Write Control, Low Enable Write
8	Vcc	Power	Power Supply

Table 1-2 Pin Definition for SOT23-5/TSOT23-5 Packages

Pin	Name	Туре	Description
1	SCL	Input	Serial Clock Input
2	GND	Ground	Ground
3	SDA	I/O	Serial Data Input and Serial Data Output
4	V <sub>cc</sub>	Power	Power Supply
5	WCB	Input	Write Control, Low Enable Write

## 1.3 Pin Descriptions

Serial Clock (SCL): The SCL input is used to clock in data at positive edge and clock out data from EEPROM at negative edge.

Serial Data (SDA): The SDA pin is bidirectional for serial data transfer. This pin is open drain driven and may be wired-OR with any number of other open-drain or open-collector devices.

Device Addresses (E2, E1, E0): The E2, E1 and E0 pins are device address inputs. Typically, the E2, E1 and E0 pins are for hardware addressing and a total of 8 devices can be connected on a single bus system. If these pins are left floating, the E2, E1 and E0 pins will be internally pulled down to GND, and the corresponding device address is fixed to 0.

Write Control (WCB): The Write Control input, when WCB is connected directly to Vcc, all write operations to the memory are inhibited. When connected to GND, allows normal write operations. If the pin is left floating, the WCB pin will be internally pulled down to GND.

# 2. Block Diagram

SCL [ Start Stop Control High Voltage Generator Logic SDA [ Serial Bus Control Logic Page Data Latch Write Control WCB □ Logic I N C MATCH X -DECODER **EEPROM ARRAY** Slave Address E0 Address Counter Comparator E1 E2 DataOut/ACK Serial MUX V<sub>cc</sub> □ GND □ Y-DECODER

Figure 2-1 Block Diagram

# 3. Electrical Characteristics

#### **Absolute Maximum Ratings**

- Storage Temperature ......-65°C to +150°C
- Operation Temperature .....-40°C to +125°C
- Maximum Operation Voltage...... 6.25V
- Voltage on Any Pin with
  - Respect to Ground ......-1.0V to (Vcc+1.0) V
- DC Output Current ...... 5.0 mA

NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 3-1 Pin Capacitance [1]

Symbol	Parameter	Max.	Units	Test Condition
C <sub>I/O</sub>	Input / Output Capacitance (SDA)	8	pF	V <sub>I/O</sub> =GND
C <sub>IN</sub>	Input Capacitance (E0, E1,E2,WCB,SCL)	6	pF	V <sub>IN</sub> =GND

Note: [1] Test Conditions:  $T_A = 25$ °C, Freq. = 1MHz, Vcc = 5.0V.

Table 3-2 DC Characteristics (Unless otherwise specified,  $V_{CC} = 1.7V$  to 5.5V,  $T_A = -40^{\circ}C$  to 125°C)

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Condition
		1.7	-	5.5	V	P24C128D-MI
Vcc	Supply Voltage	1.8	1	5.5	V	P24C128D-NK
		2.5	-	5.5	V	P24C128D-DE
		-	ı	1.0	μΑ	Vcc = 3.3V, T <sub>A</sub> = 85°C
Isb	Standby Current	-	ı	2.0	μΑ	Vcc = 5.5V, T <sub>A</sub> = 85°C
		-	ı	3.0	μΑ	Vcc = 5.5V, T <sub>A</sub> = 105°C
l	Supply Current		0.2	0.4	mA	Vcc = 5.5V,
I <sub>CC1</sub>	Supply Current	-	0.2	0.4	IIIA	Read at 400Khz
lass	Supply Current	_	0.8	1.6	mA	Vcc = 5.5V
I <sub>CC2</sub>	Зарріу Сапені	_	0.0	1.0	ША	Write at 400Khz
lu	Input Leakage Current	-	0.10	1.0	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND
I <sub>LO</sub>	Output Leakage Current	-	0.05	1.0	μΑ	V <sub>OUT</sub> = V <sub>CC</sub> or GND
$V_{IL}$	Input Low Level	-0.6	1	0.3Vcc	V	
$V_{IH}$	Input High Level	0.7V <sub>CC</sub>	-	V <sub>CC</sub> +0.5	V	
	Output Low Level			0.2	V	1
$V_{OL1}$	Vcc = 1.7V (SDA)	-		0.2	٧	I <sub>OL</sub> = 1.5 mA
V <sub>OL2</sub>	Output Low Level			0.4	V	L - 2.1 mΛ
V OL2	Vcc = 3.0V (SDA)	/ (SDA)		٧	$I_{OL} = 2.1 \text{ mA}$	
Pnd	Pull-down resistance on	5	100		МΩ	V <sub>IN</sub> = V <sub>CC</sub>
Rpd	WCB	10	30		ΚΩ	V <sub>IN</sub> < V <sub>IL</sub>

**Table 3-3 AC Characteristics** (Unless otherwise specified,  $V_{CC} = 1.7V$  to 5.5V,  $T_A = -40$ °C to 125°C,  $C_L = 100 pF$ , Test Conditions are listed in Notes [2]

Symbo	Domenton	1.7	7≤V <sub>cc</sub> <2	2.5	2.5≤V <sub>CC</sub> ≤5.5			Unito
1	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
f <sub>SCL</sub>	Clock Frequency, SCL	ı	-	400	ı	1	1000	kHz
t <sub>LOW</sub>	Clock Pulse Width Low	1.3	-	-	0.4	ı	-	μs
tнівн	Clock Pulse Width High	0.6	-	-	0.4	ı	-	μs
t <sub>AA</sub>	Clock Low to Data Out Valid	0.05	-	0.9	0.05	ı	0.55	μs
tı	Noise Suppression Time	ı	-	0.1	ı	ı	0.05	μs
t <sub>BUF</sub>	Time the bus must be free before a new transmission can start	1.3	-	-	0.5	-	-	μs
t <sub>HD.STA</sub>	START Hold Time	0.6	-	-	0.25	-	-	μs
t <sub>su.sta</sub>	START Setup Time	0.6	-	-	0.25	-	-	μs
t <sub>hd.dat</sub>	Data In Hold Time	0	-	-	0	-	-	μs
t <sub>SU.DAT</sub>	Data In Setup Time	0.1	-	-	0.1	-	-	μs
t <sub>R</sub>	Inputs Rise Time <sup>[1]</sup>	ı	-	0.3	1	1	0.3	μs
t <sub>F</sub>	Inputs Fall Time <sup>[1]</sup>	-	-	0.3	-	-	0.1	μs
t <sub>su.sto</sub>	STOP Setup Time	0.6	-	-	0.25	-	-	μs
t <sub>DH</sub>	Data Out Hold Time	0.05	-	-	0.05	1	-	μs
t <sub>SU.WCB</sub>	WCB pin Setup Time	1.2	-	-	0.6	1	-	μs
t <sub>HD.WCB</sub>	WCB pin Hold Time	1.2	-	-	0.6	-	-	μs
twR	Write Cycle Time	-	-	5	-	-	5	ms

Notes: [1] This parameter is ensured by characterization not 100% tested

[2] AC measurement conditions:

 $\Leftrightarrow~R_L$  (connects to V\_CC): 1.3k $\Omega$  (2.5V, 5.5V), 10k $\Omega$  (1.7V)

 $\diamond$  Input pulse voltages: 0.3 V<sub>CC</sub> to 0.7 V<sub>CC</sub>

♦ Input rise and fall times: ≤50ns

♦ Input and output timing reference voltages: 0.5V<sub>CC</sub>

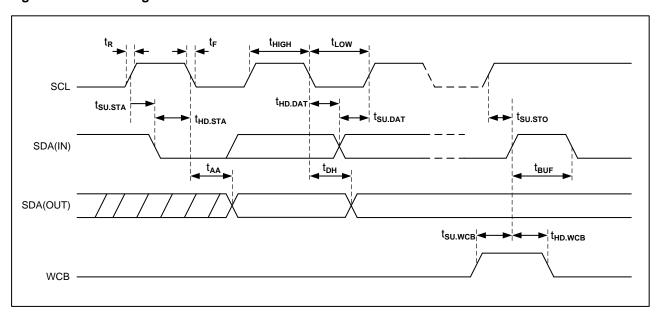
Table 3-4 Reliability Characteristics [1]

Symbol	Parameter	Min.	Тур.	Max.	Unit
EDR [2]	Endurance	1,000,000			Write cycles
DRET	Data retention	100			Years

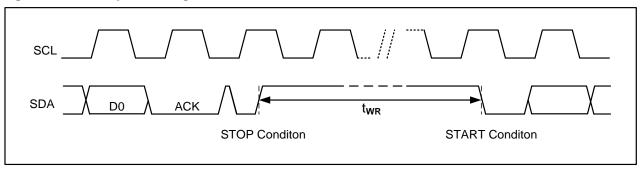
Note: [1] This parameter is ensured by characterization and is not 100% tested

[2] Under the condition: 25°C, 5.5V, Page mode

Figure 3-1 Bus Timing



**Figure 3-2 Write Cycle Timing** 



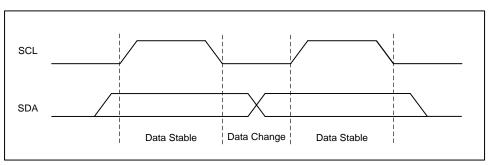
Note: [1] The write cycle time  $t_{WR}$  is the time from a valid STOP condition of a write sequence to the end of the internal clear/write cycle.

# 4. Device Operation

## 4.1 Data Input

The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low period (Refer to Figure 4-1). Data changes during SCL high period will indicate a START or STOP condition as defined below.

Figure 4-1 Data Validity



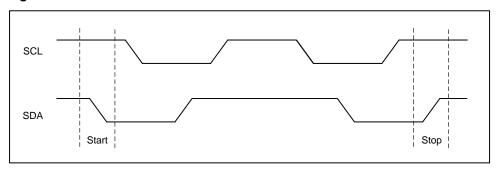
### **4.2 START Condition**

A high-to-low transition of SDA with SCL high is a START condition which must precede any other command bits. (Refer to Figure 4-2).

### 4.3 STOP Condition

A low-to-high transition of SDA with SCL high is a STOP condition. After a read sequence, the STOP bit will place the P24C128D in a standby mode (Refer to Figure 4-2).

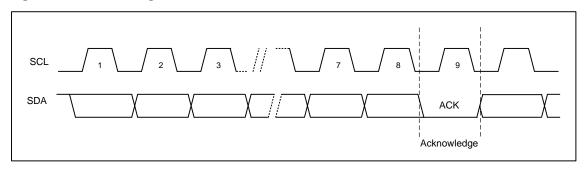
Figure 4-2 START and STOP Definition



# 4.4 Acknowledge (ACK)

All addresses and data are serially transmitted to and from the P24C128D in 8-bit data. The P24C128D sends a "0" to acknowledge that it has received each data. This happens during the ninth clock cycle.

Figure 4-3 Acknowledge Bit Definition



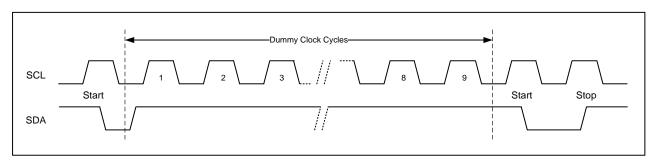
# 4.5 Standby Mode

The P24C128D features a low-power standby mode which is enabled: (a) after a fresh power up, (b) after receiving a STOP bit in read mode, and (c) after completing a self-time internal programming operation.

#### 4.6 Soft Reset

After an interruption in protocol, power loss or system reset, the device can be reset by following steps: (a) Create a START condition, (b) Clock in nine data bits "1", and (c) create another START bit followed by STOP bit condition, as shown below. The device is ready for the next communication after the above steps have been completed.

Figure 4-4 Soft Reset



### 4.7 Device Addressing

The P24C128D requires an 8-bit device address following a START condition to enable the chip for a read or write operation (Refer to table below). The device address consists of a mandatory one-zero sequence for the first four most-significant bits, as shown.

#### **Table 4-1 Device Address**

Chip	Access area	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
	Normal Area	1	0	1	0	E2	E1	E0	R/W
D24C420D	ID Page	1	0	1	1	E2	E1	E0	R/W
P24C128D	Lock Bit	1	0	1	1	E2	E1	E0	R/W
	Serial Number	1	0	1	1	E2	E1	E0	1

#### Table 4-2 Word Address0

Chip	Data	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
	Normal Area	Χ	Χ	A13	A12	A11	A10	A9	A8
P24C128D	ID Page	Х	Х	Х	Х	0	0	Х	Х
F24C126D	Lock Bit	Χ	Х	Х	Х	Х	1	Х	Х
	Serial Number	Х	Х	Х	Х	1	0	Х	Х

Table 4-3 Word Address1

Chip	Data	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
	Normal Area	A7	A6	A5	A4	A3	A2	A1	A0
D04C400D	ID Page	Х	Χ	A5	A4	А3	A2	A1	A0
P24C128D	Lock Bit	Х	Х	Х	Х	Х	Х	Х	Х
	Serial Number	Х	Х	Х	Х	A3	A2	A1	A0

The E2, E1 and E0 bits allow as many as eight devices on the same bus. These bits must compare to their corresponding hardwired input pins. The E2, E1 and E0 pins use an internal proprietary circuit that biases them to a logic low condition if the pins are floating. The bit0 of the device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low. Upon a matched comparison result, the Chip will output a zero. If not, the device will return to a standby state.

## 4.8 Data Security

P24C128D has a hardware data protection scheme that allows the user to write protect the whole memory when the WCB pin is high.

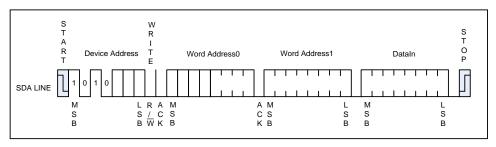
### 5. Instructions

## **5.1 Write Operations**

#### 5.1.1 Byte Write

A write operation requires an 8-bit device address following a two-byte word address and acknowledgment. Upon receipt of this device address, the P24C128D will again respond with a "0" and then clock in the first 8-bit data. Following receipt of the 8-bit data, the P24C128D will output a "0" and the master, such as a master, must terminate the write sequence with a STOP condition. And then the P24C128D enters an internally timed write cycle. All inputs are disabled during this write cycle and the P24C128D will not respond until the write is complete (Refer to Figure 5-1).

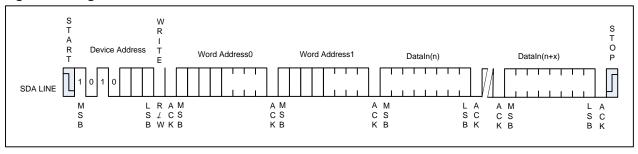
Figure 5-1 Byte Write



#### 5.1.2 Page Write

A page write is initiated in the same way as a byte write, but the master does not send a STOP condition after the first data is clocked in. Instead, after the P24C128D acknowledges receipt of the first data, the master can transmit more data continuously. The P24C128D will respond with a "0" after each data byte received. The master must terminate the page write sequence with a STOP condition.

Figure 5-2 Page Write



The lowest six bits of the word address are internally incremented following the receipt of each data. The higher word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than 64 data are transmitted to the P24C128D, the word address will roll-over and previous data will be overwritten. The address roll-over during write is from the last byte of the current page to the first byte of the same page.

#### 5.1.3 Acknowledge Polling

Once the internally timed write cycle has started, the P24C128D inputs are disabled and acknowledge polling can be initiated. This involves sending a START condition followed by the device address. The read/write bit is representative of the operation desired. Until the internal write cycle has completed will the device respond "0", allowing the read or write sequence to continue.

## 5.1.4 Write Identification Page

The Identification Page (16 bytes) is an additional page which can be written and (later) permanently locked in Read-only mode. It is written by the Write Identification Page instruction. This instruction uses the same protocol and format as Page Write (into memory array), except for the following differences:

- Device type identifier = 1011b
- Address bits A11/A10 must be '00'.
- Address bits A3/A0 define the byte address inside the Identification page.
- Other Address bits are don't care.

If the Identification page is locked, the data bytes transferred during the Write Identification Page instruction are not acknowledged (NoACK).

#### 5.1.5 Lock Identification Page

The Lock Identification Page instruction (Lock ID) permanently locks the Identification page in Read-only mode. The Lock ID instruction is similar to Byte Write (into memory array) instruction with the following specific conditions:

- Device type identifier = 1011b
- Address bit A10 must be '1'; all other address bits are don't care
- The data byte must be equal to the binary value xxxx xx1x, where x is don't care

### 5.2 Read Operations

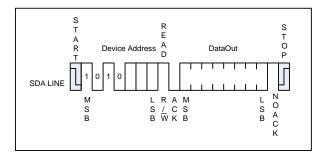
Read operations are initiated in the same way as write operations with the exception that the read/write select bit in the device address is set to "1". There are three read operations: Current Address Read; Random Address Read and Sequential Read.

#### 5.2.1 Current Address Read

The last address accessed during the last read or write operation is always incremented by one after the STOP condition of the last command. Then the Current Address Read instruction read data start from that address and increased by one after every data byte read. The address counter rolls over to the first byte of the last byte of the last memory page is encountered.

Once the device address with the read/write select bit set to "1" is clocked in and acknowledged by the device, the data at the current address is serially clocked out. The master does not respond with an input "0" but does generate a following STOP condition (Refer to Figure 5-3).

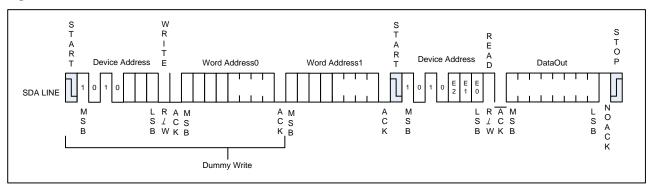
Figure 5-3 Current Address Read



#### 5.2.2 Random Read

A Random Read requires a "dummy" byte write sequence to load in the word address. Once the device address and word address are clocked in and acknowledged by the device, the master must generate another START condition. The master now initiates a Current Address Read by sending a device address with the read/write select bit high. The device acknowledges the device address and serially clocks out the data. The master does not respond with a "0" but does generate a following STOP condition (Refer to Figure 5-4).

Figure 5-4 Random Read



#### 5.2.3 Sequential Read

Sequential Reads are initiated by either a Current Address Read or a Random Address Read. After the master receives a data word, it responds with acknowledge. As long as the device receives acknowledge, it will continue to increment the word address and serially clock out sequential data. When the memory address limit is reached, the word address will roll-over and the Sequential Read will continue. The Sequential Read operation is terminated when the master does not respond with a "0" but does generate a following STOP condition (Refer to Figure 5-5)

S T W R Word Address0 Word Address1 SDA LINE A M C S K B L R A M S / C S B W K B M S L S B s В В Dummy Write S T R E A R О Р DataOut(n) Device Address DataOut(n+1) DataOut(n+x) 1 0 0 N O R A M / C S W K B L A M S C S B K B A M C S K B M S L S L S L S A C В

Figure 5-5 Sequential Read

#### 5.2.4 Read Identification Page

The Identification Page (64 bytes) is an additional page which can be written and (later) permanently locked in Read-only mode. The Identification Page can be read by Read Identification Page instruction which uses the same protocol and format as the Read Command (from memory array) with device type identifier defined as 1011b. The MSB address bits A11 and A10must be 0 and the LSB address bits A4~A0 define the byte address inside the Identification Page. The number of bytes to read in the ID page must not exceed the page boundary (e.g. when reading the Identification Page from location 58d, the number of bytes should be less than or equal to 6, as the ID page boundary is 64 bytes).

#### 5.2.5 Read the Lock Status

The locked/unlocked status of the Identification page can be checked by transmitting a specific truncated command [Identification Page Write instruction + one data byte] to the device. The device returns an acknowledge bit if the Identification page is unlocked, otherwise a No-ACK bit if the Identification page is locked.

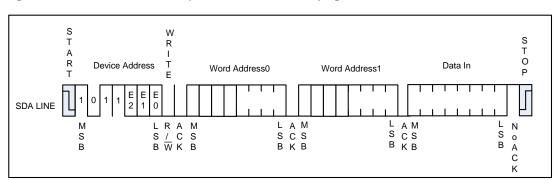


Figure 5-5 Lock Status Read (When Identification page locked, return No-ACK after the data-in)

#### 5.2.6 Read Serial Number

The Identification Page (16 bytes) is an additional page which can be written and (later) permanently locked in Read-only mode.

Reading the serial number is similar to the sequential read sequence but requires use of the device address refer to Table 4-1 on page 9, a dummy write, and the use of a specific word address. The entire 128-bit value must be read from the starting address of the serial number block to guarantee a unique number.

Since the address pointer of the device is shared between the regular EEPROM array and the serial number block, a dummy write sequence, as part of a Random Read or Sequential Read protocol, should be performed to ensure the address pointer is set to zero. A Current Address Read of the serial number block is supported but if the previous operation was to the EEPROM array, the address pointer will retain the last location accessed, incremented by one. Reading the serial number from a location other than the first address of the block will not result in a unique serial number.

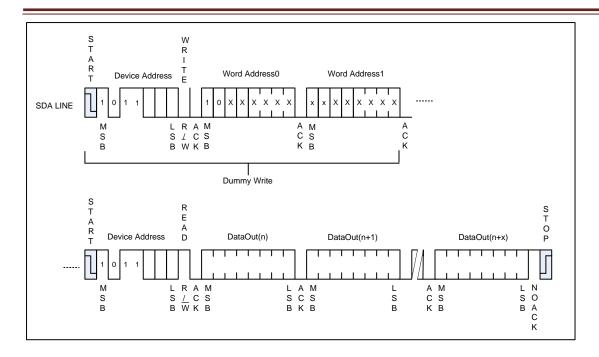
Additionally, the word address contains a '10' sequence in bit A11 and A10 of the word address, regardless of

the intended address as depicted in Table 4-2 on page 9. If a word address other than '10' is used, then the device will output undefined data.

Example: If the application desires to read the first byte of the serial number, the word address input would need to be 0800h.

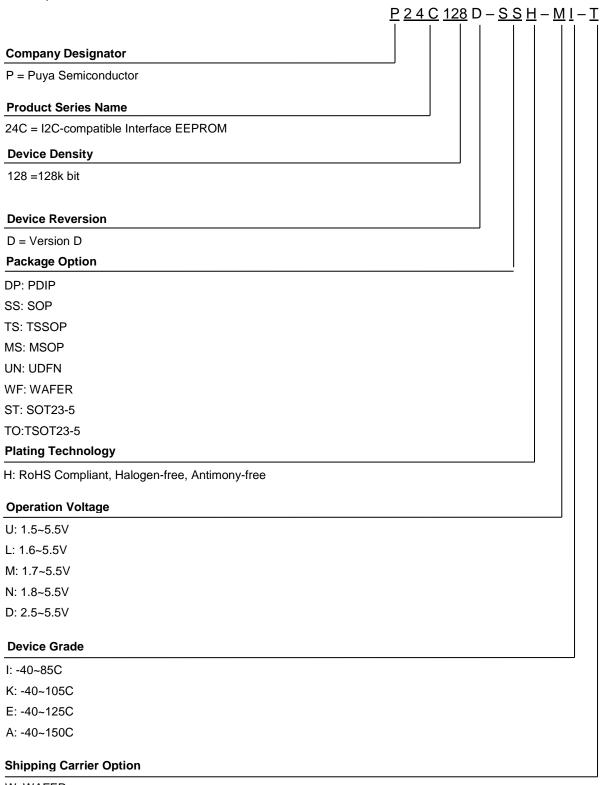
When the end of the 128-bit serial number is reached (16 bytes of data), continued reading of the extended memory region will result in an repeated 16 bytes data. Upon reaching the end of the 16-byte extended memory region, the word address will roll-over back to the beginning of the 128-bit serial number. The Serial Number Read operation is terminated when the master does not respond with a zero (ACK) and instead issues a STOP condition (Refer to Figure 5-6)

Figure 5-6 Sequential Read



# 6. Ordering Code Detail





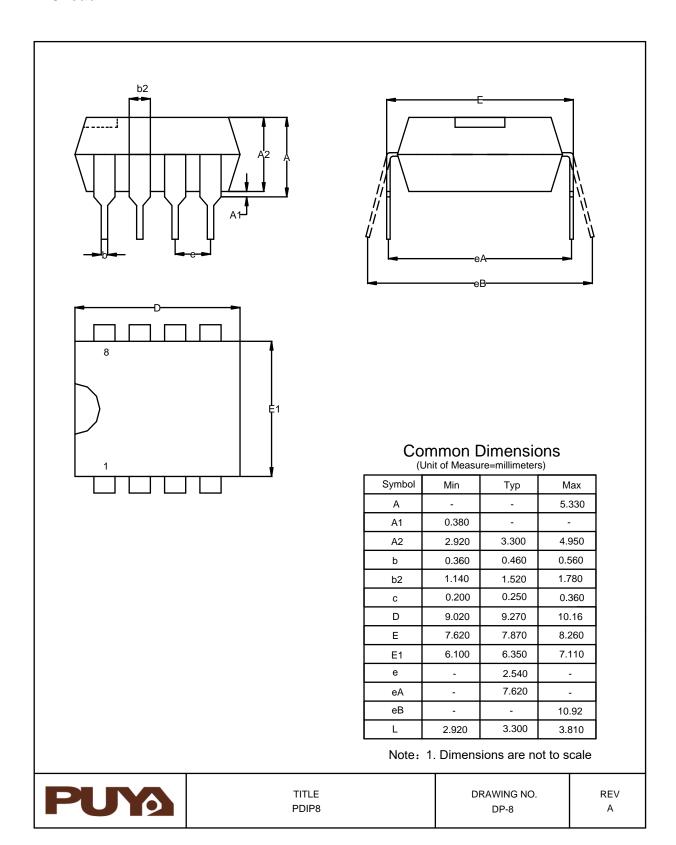
W: WAFER

T: TUBE

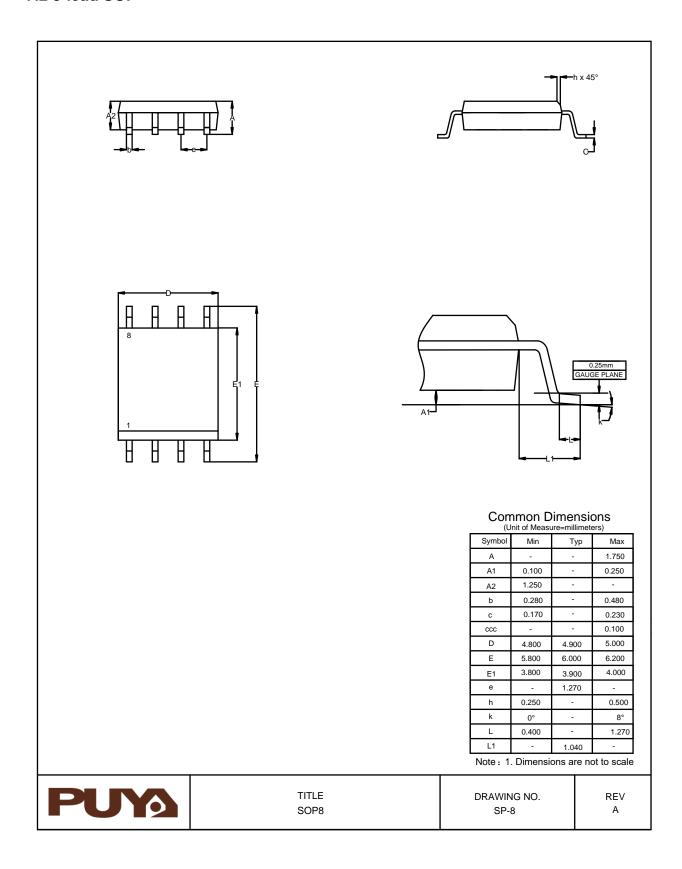
R:TAPE & REEL

# 7. Package information

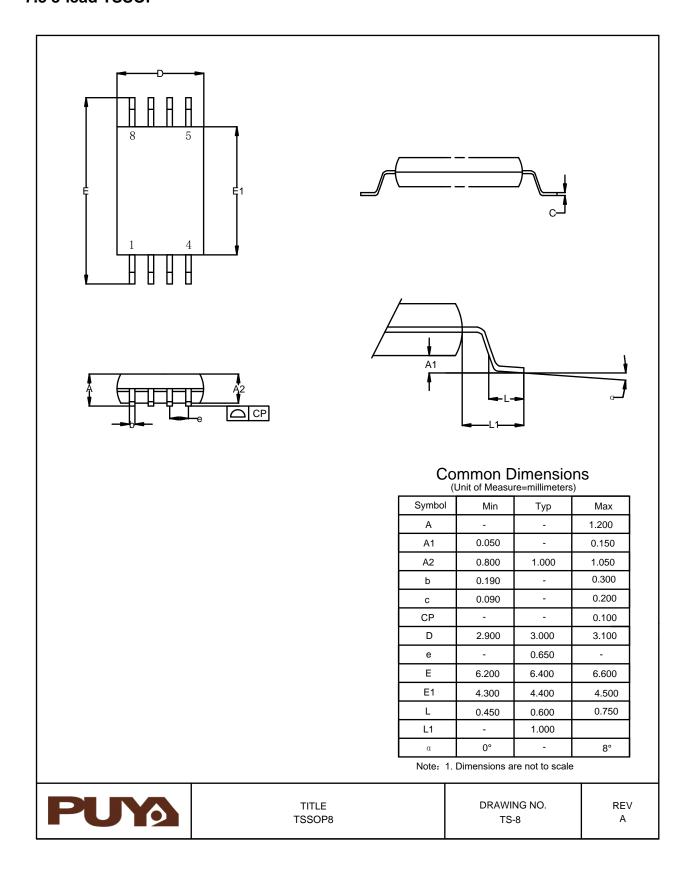
## 7.1 8-lead PDIP



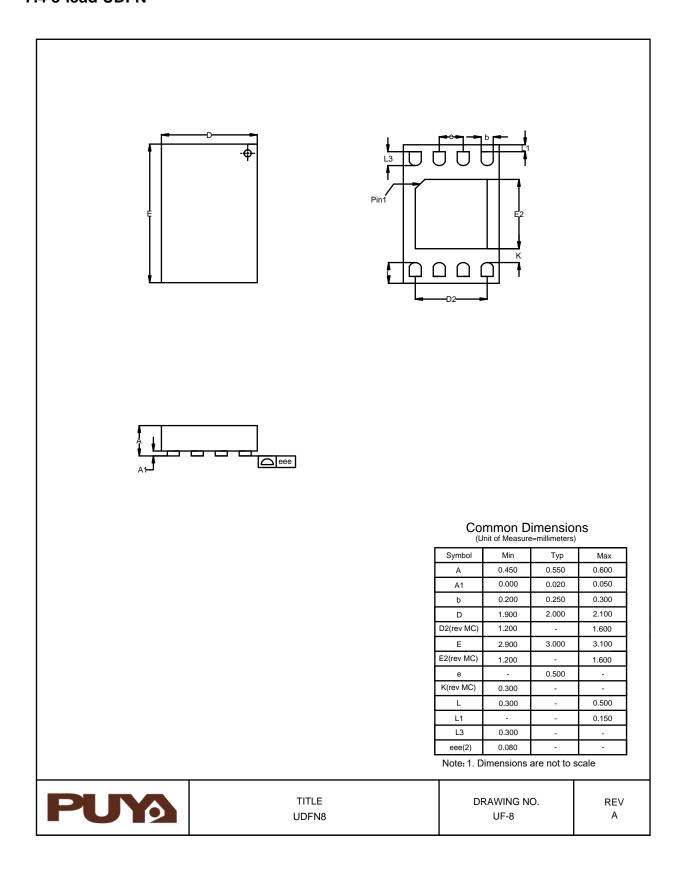
# 7.2 8-lead SOP



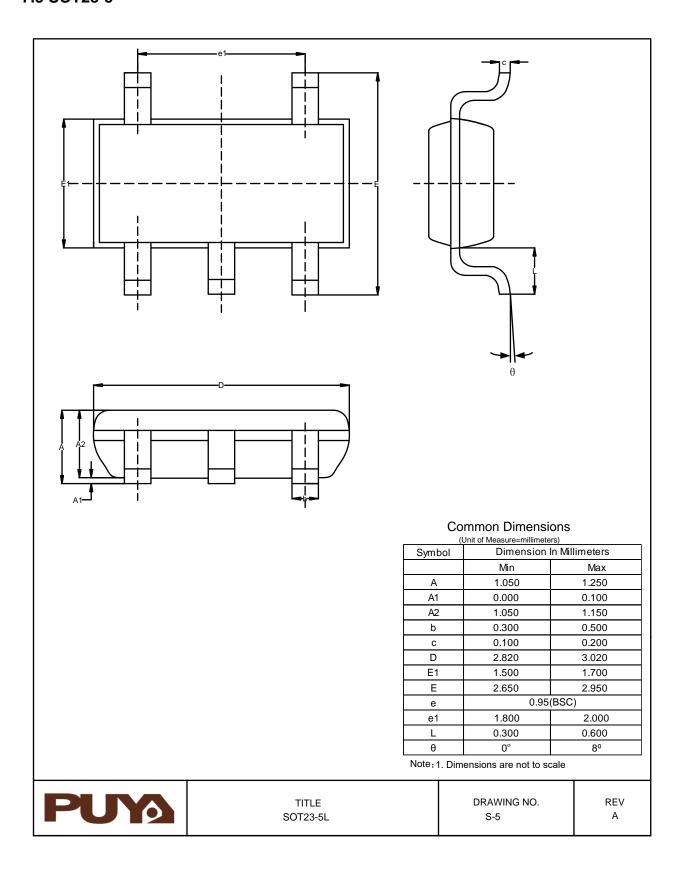
## 7.3 8-lead TSSOP



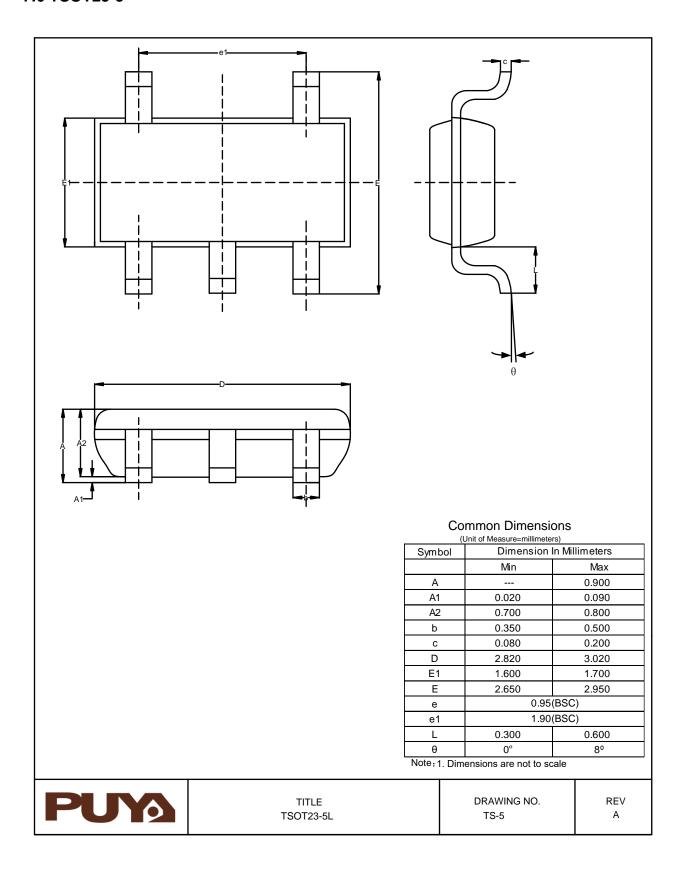
# 7.4 8-lead UDFN



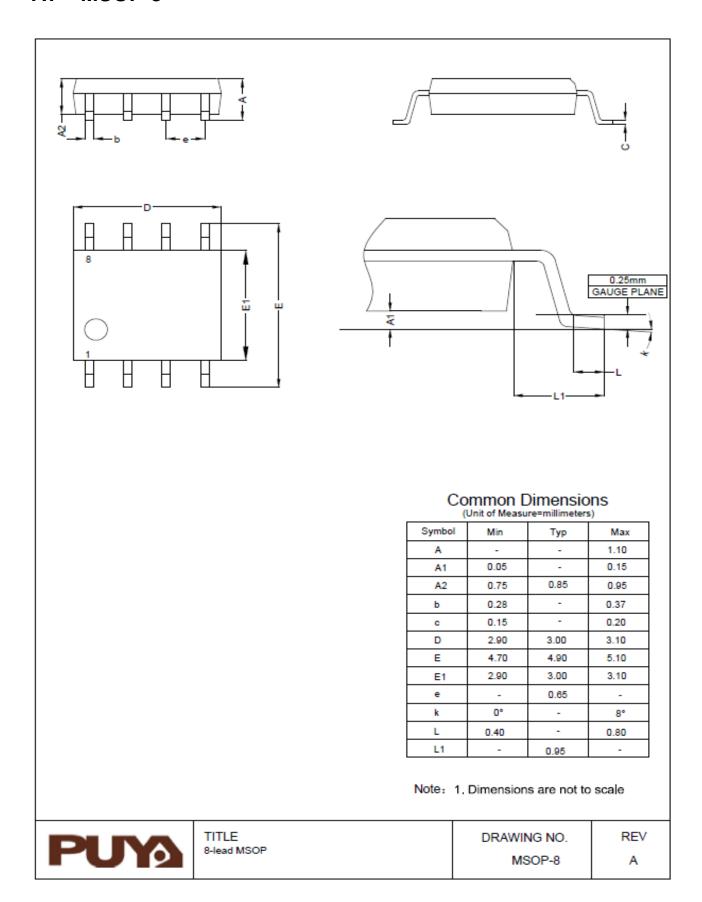
# 7.5 SOT23-5



# 7.6 TSOT23-5



# 7.7 MSOP-8



# 8. Revision History

Version	Content	Date
Rev 1.0	Initial Release	2016-11-11
Rev 1.1	1) Remove WLCSP Package	2016-12-01
Rev 1.2	<ol> <li>Correct command waveform from one byte word address to two bytes word address.</li> <li>Correct the descriptions for read and write instruction</li> <li>Add Rpd in DC characteristics</li> </ol>	2017-03-08
Rev 1.3	1)Add package MSOP-8	2019-04-17



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